Freeform Search

Database:

US Pre-Grant Publication Full-Text Database
US Patents Full-Text Database
US OCR Full-Text Database
EPO Abstracts Database
JPO Abstracts Database
Derwent World Patents Index
IBM Technical Disclosure Bulletins

Term:

L11 and @ad<20040106

Display: 10 Documents in **Display Format:** - **Starting with Number** 1

Generate: ○ Hit List ⊙ Hit Count ○ Side by Side ○ Image

Search   Clear   Interrupt

Search History

DATE: Tuesday, October 23, 2007   **Purge Queries**   Printable Copy   Create Case

Set Name side by side	Query	Hit Count	Set Name result set
DB=JPAB,DWPI,TDBD; PLUR=YES; OP=OR			
L12	L11 and @ad<20040106	55647	L12
L11	L10 and 5	64075	L11
L10	2 near4 (electrode)	124328	L10
L9	L8 and @ad<20040106	1334336	L9
L8	2 near5 3	1623717	L8
L7	4 and 5	4116387	L7
L6	4 and 5	4116387	L6
L5	bipolar	52325	L5
L4	2 with L3	1223986	L4
L3	electrode or electrodes or contact or contacts or layer or layers or film or films or region or regions or area or areas or pattern or patterns	7010497	L3
L2	(indium near8 nitride) or "InAlGaAsN" or "InGaN" or "InAsN" or "InN" or "InAlGaN" or "AllnGanN" or "GaNAlIn" or "GaAlInN" or "AlGaNIn" or "AlGaInN"	4527	L2
DB=USPT; PLUR=YES; OP=OR			

L1	(indium near8 nitride) or "InAlGaAsN" or "InGaN" or "InAsN" or "InN" or "InAlGaN" or "AlInGanN" or "GaNAlIn" or "GaAlInN" or "AlGaNIn" or "AlGaInN"	8523	L1

END OF SEARCH HISTORY